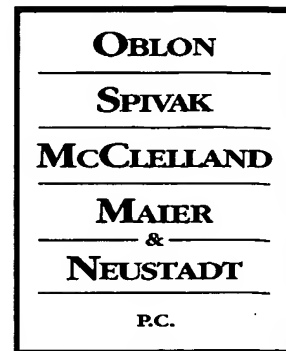




RESPONSE UNDER 37 CFR 1.116-
EXPEDITED PROCEDURE EXAMINING
GROUP 2811



Docket No.: 246155US2SRD

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

ATTORNEYS AT LAW

RE: Application Serial No.: 10/726,705
Applicants: Masato KOYAMA, et al.
Filing Date: December 4, 2003
For: A METHOD OF FORMING A SEMICONDUCTOR
DEVICE HAVING AN
AMORPHOUS/CRYSTALLINE GATE INSULATING
LAYER
Group Art Unit: 2811
Examiner: HU, S.

SIR:

Attached hereto for filing are the following papers:

REQUEST FOR RECONSIDERATION UNDER 37 C.F.R. § 1.116

Our check in the amount of - is attached covering any required fees. In the event any variance exists between the amount enclosed and the Patent Office charges for filing the above-noted documents, including any fees required under 37 C.F.R. 1.136 for any necessary Extension of Time to make the filing of the attached documents timely, please charge or credit the difference to our Deposit Account No. 15-0030. Further, if these papers are not considered timely filed, then a petition is hereby made under 37 C.F.R. 1.136 for the necessary extension of time. A duplicate copy of this sheet is enclosed.

Respectfully submitted,

OBLON, SPIVAK, McCLELLAND,
MAIER & NEUSTADT, P.C.

Eckhard H. Kuesters

Registration No. 28,870

Customer Number

22850

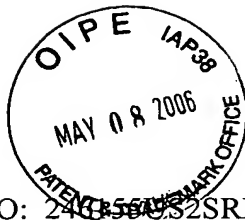
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Remus F. Fetea, Ph.D.

Limited Recognition No. L0037



"RESPONSE UNDER 37 CFR 1.116-
EXPEDITED PROCEDURE EXAMINING
GROUP 2811"

DOCKET NO: 2461560US2SRD

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :
MASATO KOYAMA, ET AL. : EXAMINER: HU, S.
SERIAL NO: 10/726,705 :
RCE FILED: MARCH 7, 2005 : GROUP ART UNIT: 2811
FOR: A METHOD OF FORMING A :
SEMICONDUCTOR DEVICE
HAVING AN
AMORPHOUS/CRYSTALLINE
GATE INSULATING LAYER

REQUEST FOR RECONSIDERATION UNDER 37 C.F.R. § 1.116

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

SIR:

In response to the Office Action dated March 8, 2006, Applicants respectfully request reconsideration of the above-identified application in view of the following remarks.

Remarks/Arguments begin on page 2 of this paper.